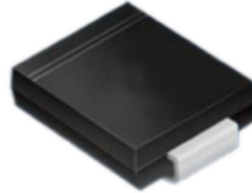


Features

- Fast switching speed.
- Low profile surface mounted application in order to optimize board space.
- Surface mount package ideally suited for automatic insertion.
- Low power loss, high efficiency.
- High forward surge current capability.
- Lead-free parts meet RoHS requirements.
- Compliant to Halogen-free



DO-214AB(SMC)

Mechanical data

- Epoxy:UL94-V0 rated flame retardant
- Case : Molded plastic, DO-214AB/SMC
- Terminals : Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity : Indicated by cathode band
- Mounting Position : Any

Maximum ratings and Electrical Characteristics (AT $T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Forward rectified current	See Fig.2	I_o			4.0	A
Forward surge current	8.3ms single half sine-wave (JEDEC methode)	I_{FSM}			100	A
Reverse current	$V_R = V_{RRM} \quad T_A = 25^{\circ}\text{C}$	I_R			5.0	μA
	$V_R = V_{RRM} \quad T_A = 100^{\circ}\text{C}$				50	
Thermal resistance	Junction to ambient NOTE 1	R_{BJA}		40		$^{\circ}\text{C}/\text{W}$
Diode junction capacitance	f=1MHz and applied 4V DC reverse voltage	C_J		70		pF
Storage temperature		T_{STG}	-65		+175	$^{\circ}\text{C}$

SYMBOLS	V_{RRM}^{*1} (V)	V_{RMS}^{*2} (V)	V_R^{*3} (V)	V_F^{*4} (V)	trr^{*5} (ns)	Operating temperature T_J , ($^{\circ}\text{C}$)
MURS320T3G-JSM	200	140	200	0.89	25	-55 to +150

Note 1. Reverse recovery time test condition, $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{RR}=0.25\text{A}$

*1 Repetitive peak reverse voltage

*2 RMS voltage

*3 Continuous reverse voltage

*4 Maximum forward voltage@ $I_F=4.0\text{A}$

*5 Maximum Reverse recovery time, note 1

Rating and characteristic curves

FIG.1-TYPICAL FORWARD CHARACTERISTICS

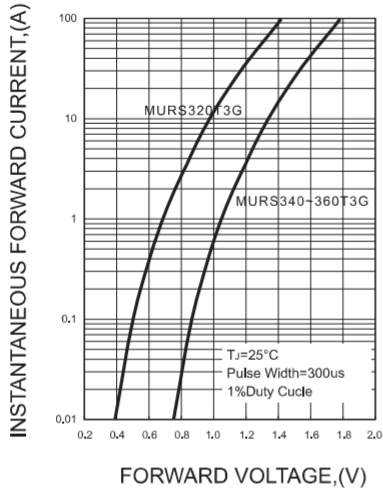


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

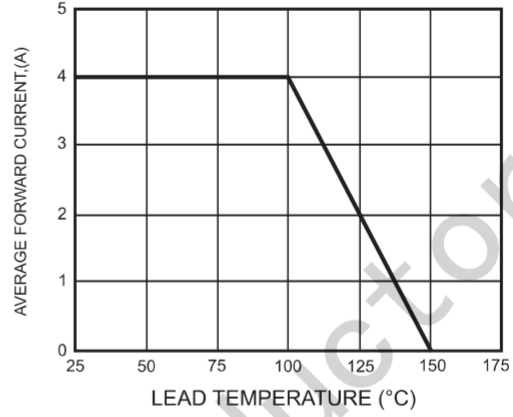


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

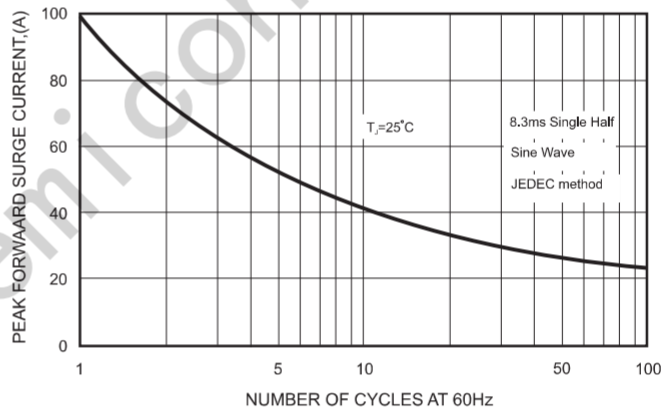
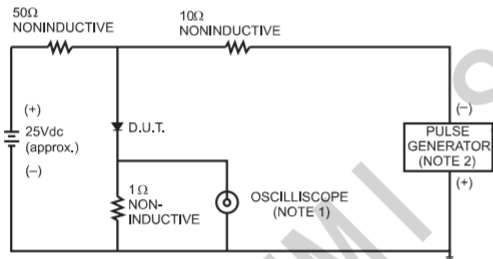


FIG.3- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTICS



NOTES: 1. Rise Time = 7ns max., Input Impedance = 1 megohm, 22pF.
2. Rise Time = 10ns max., Source Impedance = 50 ohms.

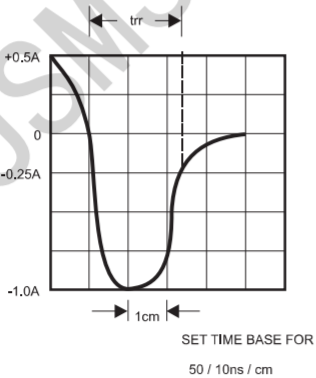
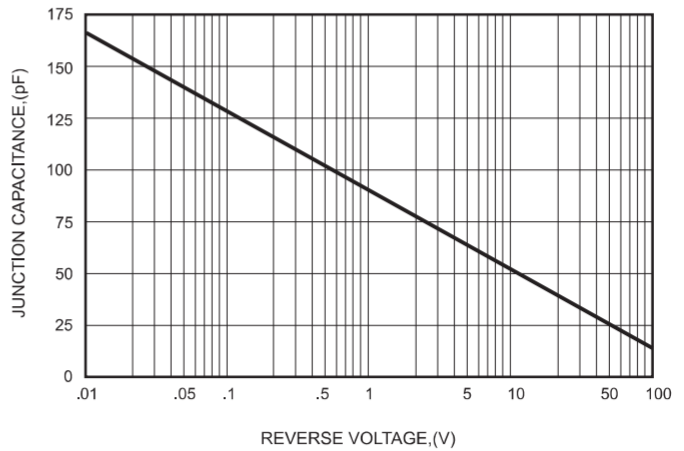


FIG.5-TYPICAL JUNCTION CAPACITANCE



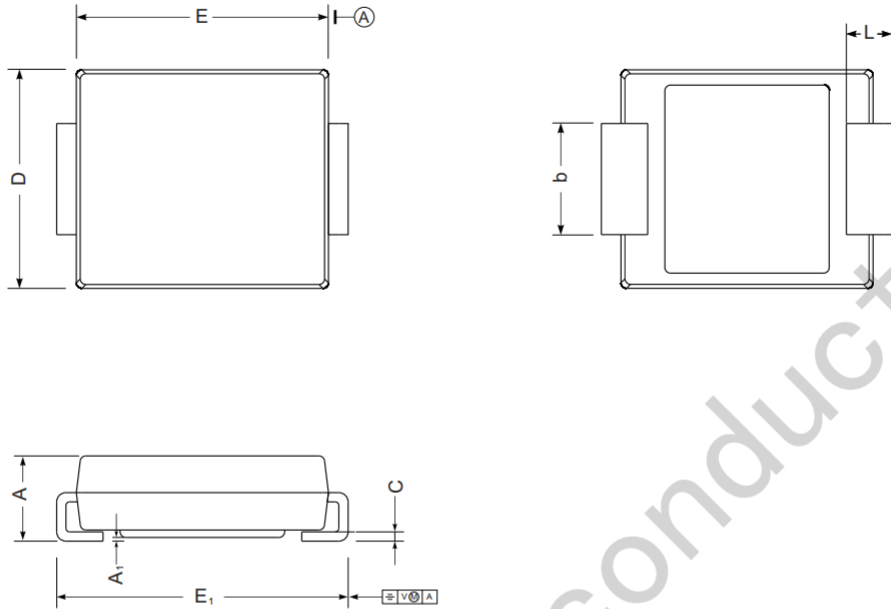
Pinning information

Pin	Simplified outline	Symbol
Pin1 cathode Pin2 anode		

JSMSEMI Semiconductor

Package Information

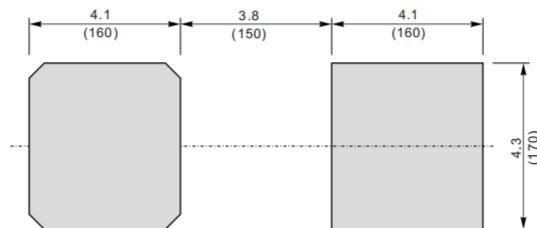
SMC



SMC mechanical data

UNIT		A	E	D	E ₁	A ₁	C	L	b
mm	max	2.62	7.0	6.2	8.0	0.21	0.31	1.6	3.25
	min	2.00	6.5	5.6	7.6	0.05	0.15	0.9	2.75
mil	max	103	276	244	315	8.3	12	63	128
	min	79	256	220	299	2.0	5.9	35	108

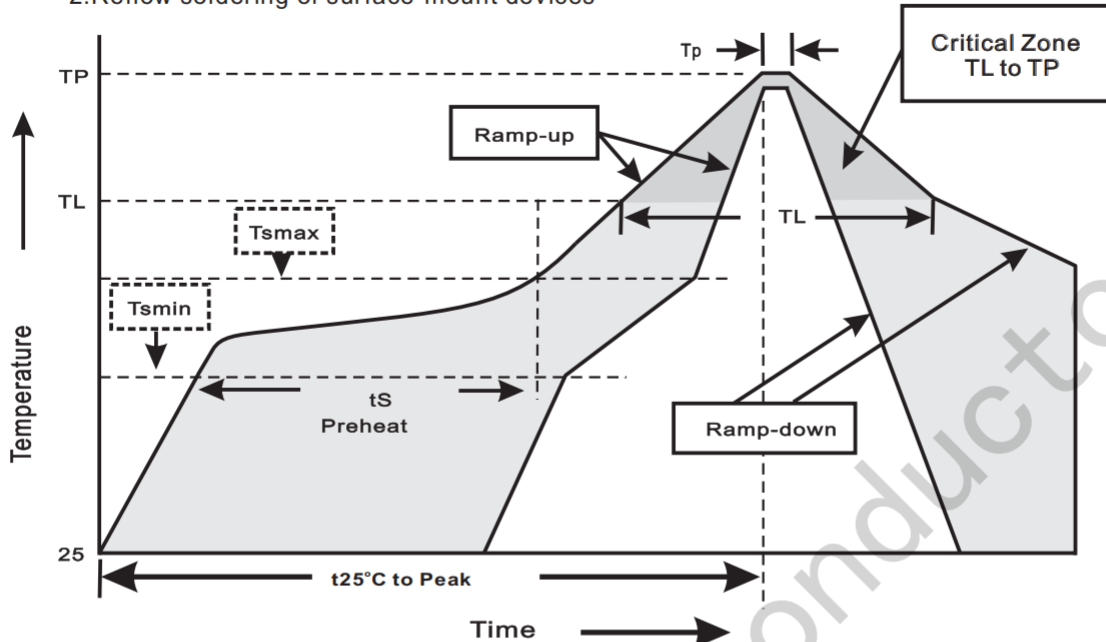
The recommended mounting pad size



Unit : $\frac{\text{mm}}{\text{mil}}$

Suggested thermal profiles for soldering processes

- 1.Storage environment: Temperature=5°C~40°C Humidity=55%±25%
- 2.Reflow soldering of surface-mount devices



3.Reflow soldering

Profile Feature	Soldering Condition
Average ramp-up rate(TL to Tp)	<3°C/sec
Preheat - Temperature Min(Tsmin) - Temperature Max(Tsmax) - Time(min to max)(ts)	150°C 200°C 60~120sec
Tsmax to TL - Ramp-upRate	<3°C/sec
Time maintained above: - Temperature(TL) - Time(tL)	217°C 60~260sec
Peak Temperature(Tp)	255°C-0/+5°C
Time within 5°C of actual Peak Temperature(tp)	10~30sec
Ramp-down Rate	<6°C/sec
Time 25°C to Peak Temperature	<6minutes